NSN 5962-01-554-3769

Memory Microcircuit - Page 1 of 1



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Bodv	Length:

- 0.713 inches
- **Body Width:**
- 0.299 inches

Body Height:

0.104 inches

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Features Provided:

Low power and high reliability and erasable and programmable

Inclosure Material:

Plastic

Inclosure Configuration:

Flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

20.00 milliamperes forward current, nonrepetitive, peak total value blank

Product Name:

Parallel battery-voltage eeprom

Voltage Rating And Type Per Characteristic:

3.6 volts total supply

Time Rating Per Chacteristic:

200.00 nanoseconds access

Memory Device Type:

Rom

Memory Capacity:

8192 x 8 bit

Terminal Type And Quantity:

28 gullwing

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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